

# PBHV8550X

500 V, 150 mA NPN high-voltage low V<sub>CEsat</sub> (BISS) transistor

8 June 2020

Product data sheet

## 1. General description

NPN high-voltage low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor in a medium power SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- AEC-Q101 qualified

## 3. Applications

- Electronic ballasts
- LED driver for LED chain module
- LCD backlighting
- Automotive motor management
- Flyback converters
- Switch Mode Power Supply (SMPS)

## 4. Quick reference data

Table 1. Quick reference data

| Symbol           | Parameter                 | Conditions   | Min | Typ | Max | Unit |
|------------------|---------------------------|--|-----|-----|-----|------|
| V <sub>CEO</sub> | collector-emitter voltage | open base  | -   | -   | 500 | V    |
| I <sub>C</sub>   | collector current         |  | -   | -   | 150 | mA   |
| h <sub>FE</sub>  | DC current gain           | V <sub>CE</sub> = 10 V; I <sub>C</sub> = 30 mA; T <sub>amb</sub> = 25 °C | 50  | 100 | -   |      |

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--------------------|----------------|
| 1   | E      | emitter     | <p>SOT89</p>       | <p>sym123</p>  |
| 2   | C      | collector   |                    |                |
| 3   | B      | base        |                    |                |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |
|-------------|---------|--|---------|
|             | Name    | Description  | Version |
| PBHV8550X   | SOT89   | plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body | SOT89   |

## 7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBHV8550X   | C8           |

## 8. Limiting values

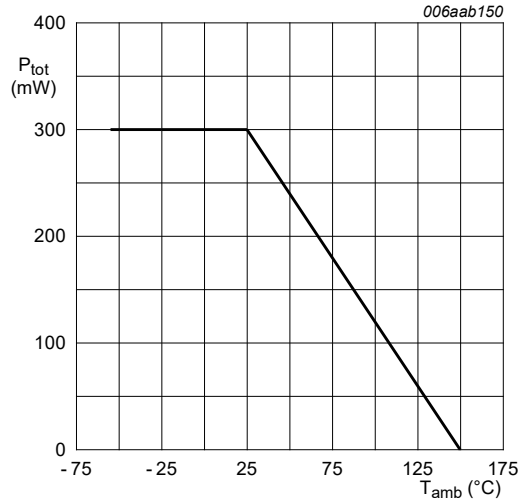
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol     | Parameter                      | Conditions                    |     | Min | Max | Unit |
|------------|--------------------------------|-------------------------------|-----|-----|-----|------|
| $V_{CBO}$  | collector-base voltage         | open emitter                  |     | -   | 500 | V    |
| $V_{CEO}$  | collector-emitter voltage      | open base                     |     | -   | 500 | V    |
| $V_{CESM}$ | collector-emitter peak voltage | $V_{BE} = 0$ V                |     | -   | 500 | V    |
| $V_{EBO}$  | emitter-base voltage           | open collector                |     | -   | 6   | V    |
| $I_C$      | collector current              |                               |     | -   | 150 | mA   |
| $I_{CM}$   | peak collector current         | single pulse; $t_p \leq 1$ ms |     | -   | 0.5 | A    |
| $I_{BM}$   | peak base current              |                               |     | -   | 200 | mA   |
| $P_{tot}$  | total power dissipation        | $T_{amb} \leq 25$ °C          | [1] | -   | 520 | mW   |
|            |                                |                               | [2] | -   | 1.5 | W    |
| $T_j$      | junction temperature           |                               |     | -   | 150 | °C   |
| $T_{amb}$  | ambient temperature            |                               |     | -55 | 150 | °C   |
| $T_{stg}$  | storage temperature            |                               |     | -65 | 150 | °C   |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Fig. 1. Power derating curve

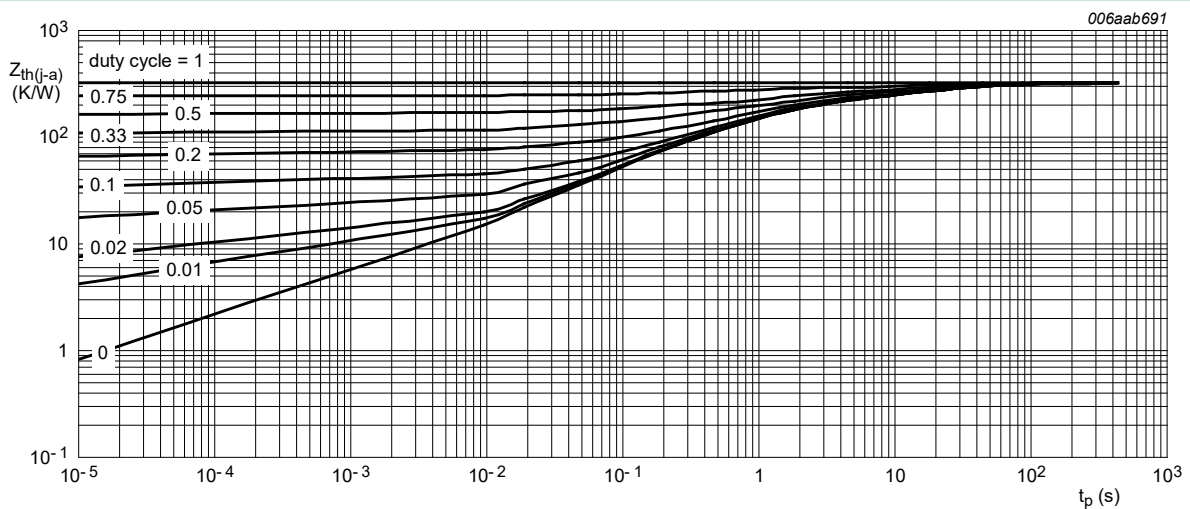
## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter  | Conditions  |     | Min | Typ | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | [1] | -   | -   | 241 | K/W  |
|                       |  |             | [2] | -   | -   | 84  | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             |     | -   | -   | 20  | K/W  |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.



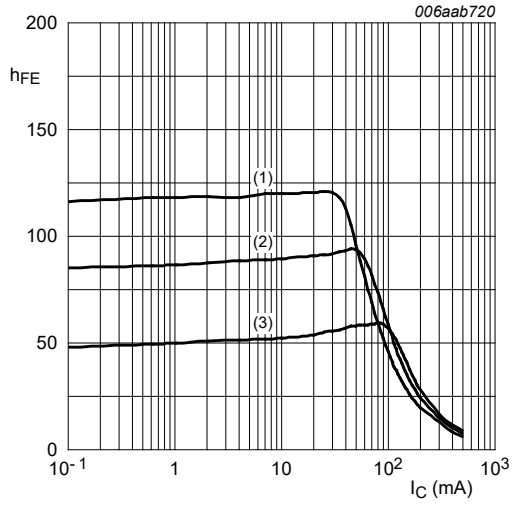
FR4 PCB, standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 10. Characteristics

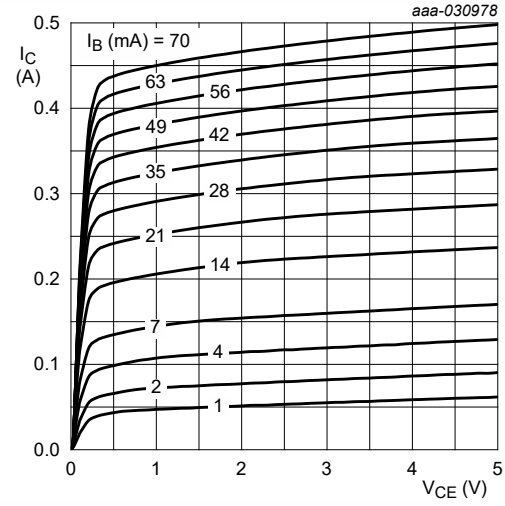
Table 7. Characteristics

| Symbol           | Parameter  | Conditions  | Min  | Typ  | Max | Unit          |
|------------------|--|---|--|------|-----|---------------|
| $V_{(BR)CBO}$    | collector-base breakdown voltage                   | $I_C = 100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  | 500  | -    | -   | V             |
| $V_{(BR)CES}$    | collector-emitter breakdown voltage (base shorted) | $I_C = 2.5 \text{ mA}$ ; $V_{BE} = 0 \text{ V}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  | 500  | -    | -   | V             |
| $V_{(BR)EBO}$    | emitter-base breakdown voltage (collector open)    | $I_E = 100 \mu\text{A}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  | 6  | -    | -   | V             |
| $I_{CBO}$        | collector-base cut-off current                     | $V_{CB} = 360 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$   | -  | -    | 100 | nA            |
|                  |  | $V_{CB} = 360 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$   | -  | -    | 50  | $\mu\text{A}$ |
| $I_{CES}$        | collector-emitter cut-off current                  | $V_{CE} = 360 \text{ V}$ ; $V_{BE} = 0 \text{ V}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  | -  | -    | 100 | nA            |
| $I_{EBO}$        | emitter-base cut-off current                       | $V_{EB} = 5 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$   | -  | -    | 100 | nA            |
| $h_{FE}$         | DC current gain                                    | $V_{CE} = 10 \text{ V}$ ; $I_C = 30 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$  | 50   | 100  | -   |               |
|                  |  | $V_{CE} = 10 \text{ V}$ ; $I_C = 50 \text{ mA}$ ; $t_p \leq 300 \mu\text{s}$ ; pulsed; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$              | 50   | 100  | -   |               |
| $V_{CEsat}$      | collector-emitter saturation voltage               | $I_C = 20 \text{ mA}$ ; $I_B = 2 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$   | -  | 60   | 75  | mV            |
|                  |  | $I_C = 50 \text{ mA}$ ; $I_B = 6 \text{ mA}$ ; $t_p \leq 300 \mu\text{s}$ ; pulsed; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$                 | -  | 65   | 90  | mV            |
| $V_{BEsat}$      | base-emitter saturation voltage                    | $I_C = 50 \text{ mA}$ ; $I_B = 5 \text{ mA}$ ; $t_p \leq 300 \mu\text{s}$ ; pulsed; $\delta \leq 0.02$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$                 | -  | 0.75 | 0.9 | V             |
| $t_d$            | delay time   | $V_{CC} = 20 \text{ V}$ ; $I_C = 0.05 \text{ A}$ ; $I_{B\text{on}} = 5 \text{ mA}$ ; $I_{B\text{off}} = -5 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | -  | 80   | -   | ns            |
| $t_r$            | rise time  |   | -  | 2700 | -   | ns            |
| $t_{\text{on}}$  | turn-on time                                       |   | -  | 2780 | -   | ns            |
| $t_s$            | storage time                                       |   | -  | 3400 | -   | ns            |
| $t_f$            | fall time  |   | -  | 800  | -   | ns            |
| $t_{\text{off}}$ | turn-off time                                      |   | -  | 4200 | -   | ns            |
| $f_T$            | transition frequency                               |   | $V_{CE} = 10 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | -    | 35  | -             |
| $C_c$            | collector capacitance                              | $V_{CB} = 20 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$                              | -  | 4    | -   | pF            |
| $C_e$            | emitter capacitance                                | $V_{EB} = 0.5 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $i_c = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$                             | -  | 200  | -   | pF            |



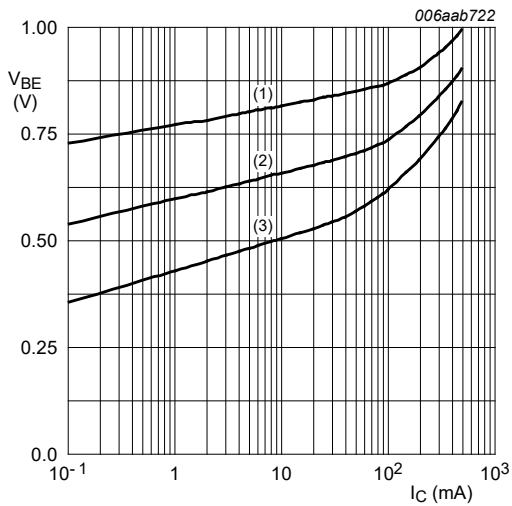
$V_{CE} = 10\text{ V}$   
 (1)  $T_{amb} = 100^\circ C$   
 (2)  $T_{amb} = 25^\circ C$   
 (3)  $T_{amb} = -55^\circ C$

Fig. 3. DC current gain as a function of collector current; typical values



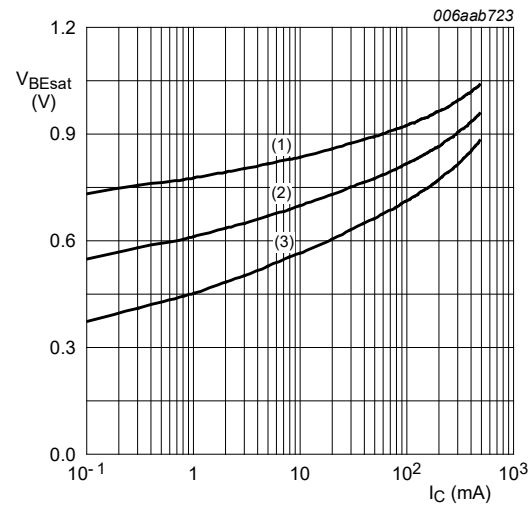
$T_{amb} = 25^\circ C$

Fig. 4. Collector current as a function of collector-emitter voltage; typical values



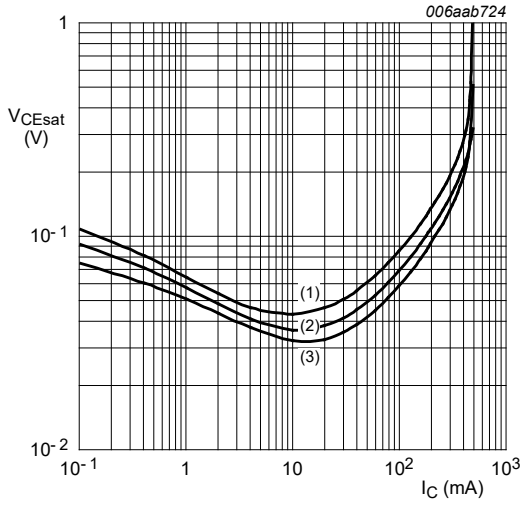
$V_{CE} = 10\text{ V}$   
 (1)  $T_{amb} = -55^\circ C$   
 (2)  $T_{amb} = 25^\circ C$   
 (3)  $T_{amb} = 100^\circ C$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



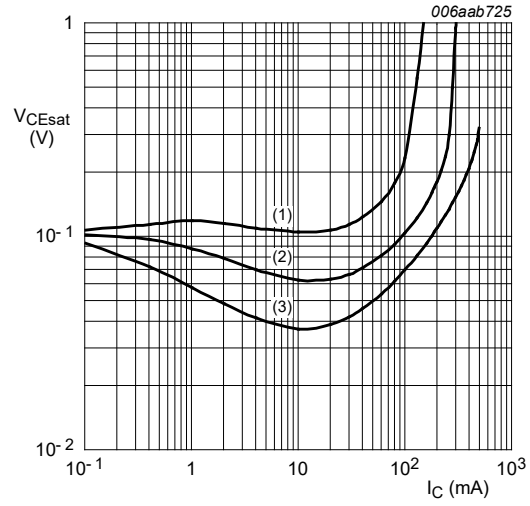
$I_C/I_B = 5$   
 (1)  $T_{amb} = -55^\circ C$   
 (2)  $T_{amb} = 25^\circ C$   
 (3)  $T_{amb} = 100^\circ C$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



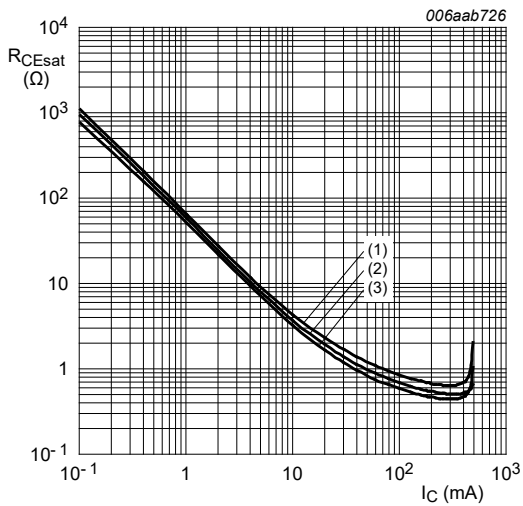
$I_C/I_B = 5$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values**



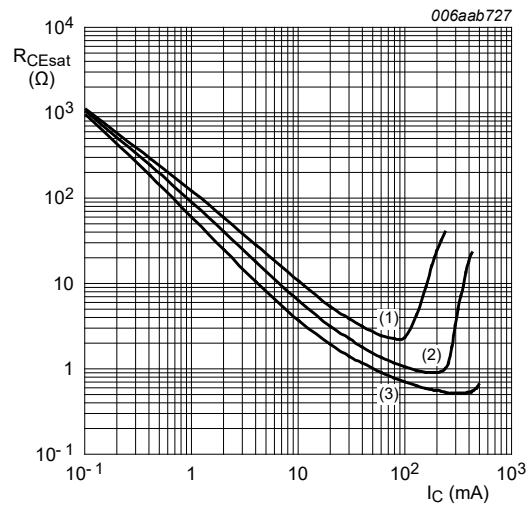
$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 20$   
 (2)  $I_C/I_B = 10$   
 (3)  $I_C/I_B = 5$

**Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values**



$I_C/I_B = 5$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig. 9. Collector-emitter saturation resistance as a function of collector current; typical values**



$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 20$   
 (2)  $I_C/I_B = 10$   
 (3)  $I_C/I_B = 5$

**Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values**

### 11. Test information

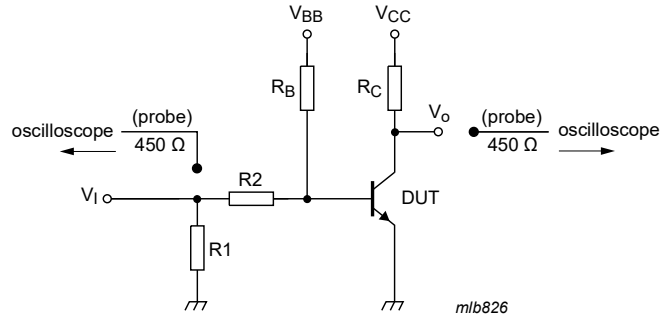


Fig. 11. Test circuit for switching times

#### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 12. Package outline

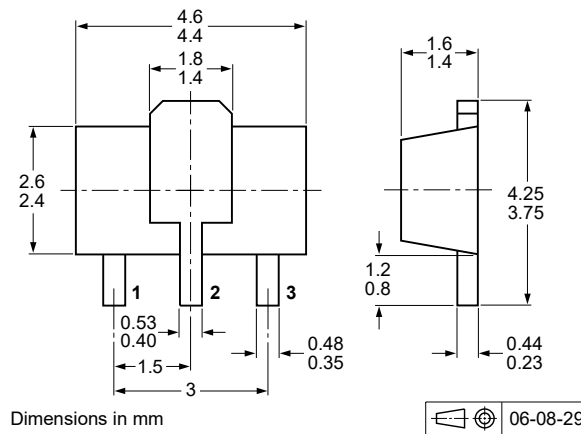


Fig. 12. Package outline SOT89

### 13. Soldering

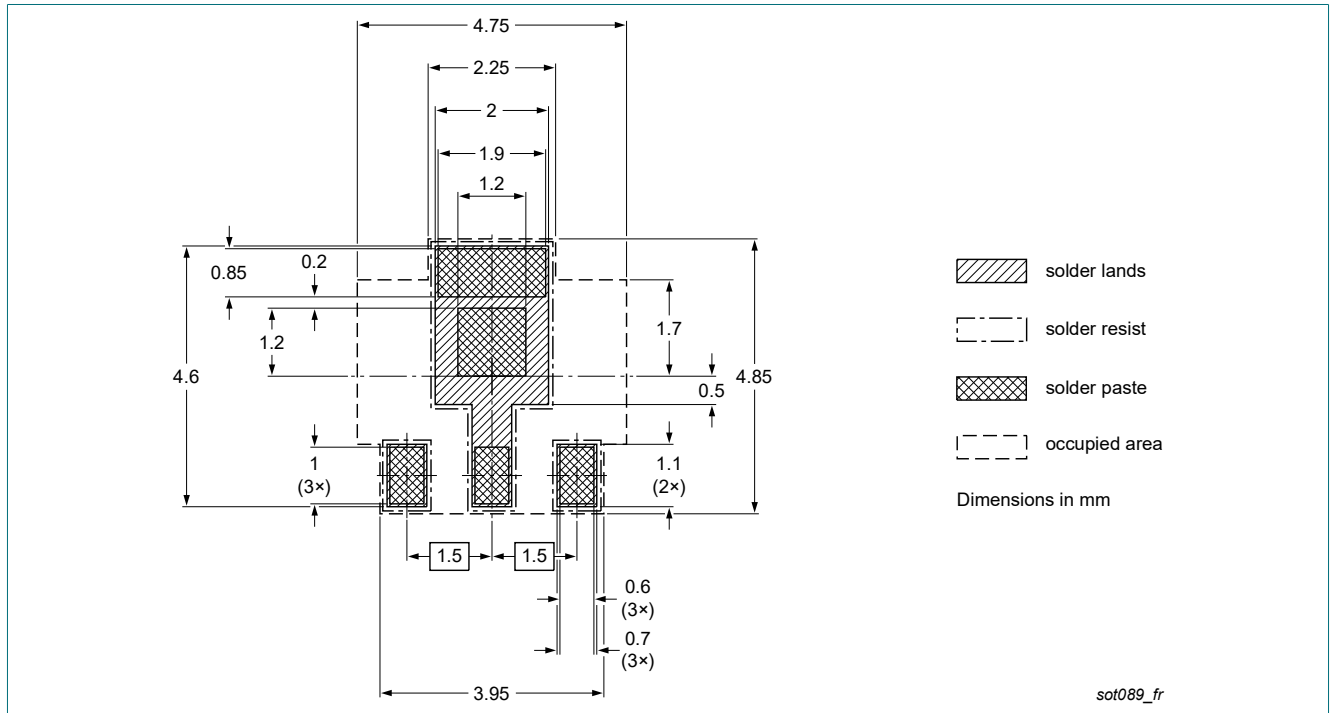


Fig. 13. Reflow soldering footprint for SOT89

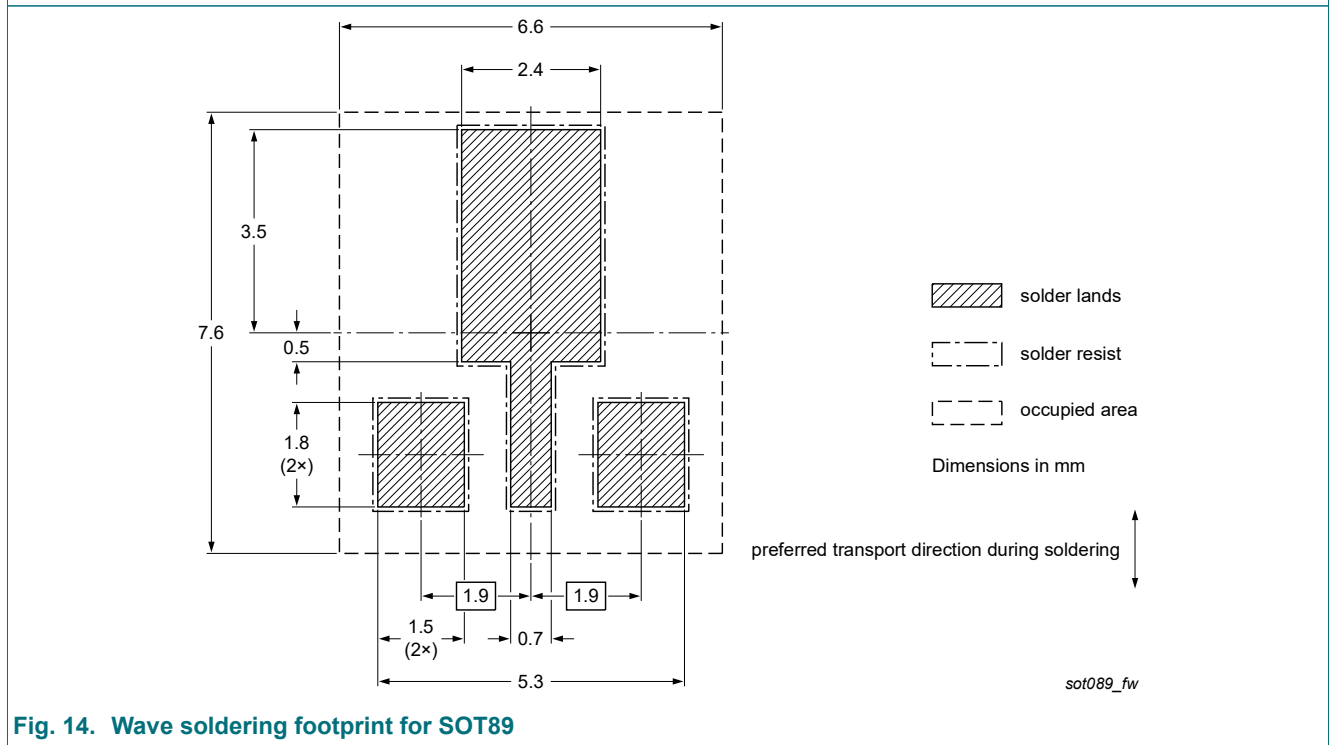


Fig. 14. Wave soldering footprint for SOT89



## 14. Revision history

**Table 8. Revision history**

| Data sheet ID  | Release date                              | Data sheet status    | Change notice | Supersedes    |
|----------------|---|----------------------|---------------|---------------|
| PBHV8550X v.3  | 20200608                                  | Product data sheet   | -             | PBHV8550X v.2 |
| Modifications: | • Figure 4 updated with additional curves |                      |               |               |
| PBHV8550X v.2  | 20200214                                  | Objective data sheet | -             | PBHV8550X v.1 |
| PBHV8550X v.1  | 20200130                                  | Objective data sheet | -             | -             |

## 15. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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